2/24/04

FORM PTO-1449 (MODIFIED)					ATTY DOCKET	SERIAL NO. 10/789,527			
LIST OF PATENTS AND PUBLICATIONS					67,200-1247	10/70/509/			
FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT					Applicant: Kuo-Chi Tu				
DISCLOSURE STATEWENT					FILING DATE	GROUP Unknown			
(Use several sheets if necessary)					Filed Herewith 2822				
REFERENCE DESIGNATION U.S. PATENT DOCUMENTS									
EXAMINER INITIAL		DOCUMENT NO.	DATE		NAME C		CLASS	SUB	FILING DATE
MP	AA	5,360,753	11/199	94	Park et al				
MP	АВ	5,696,021	12/199	97	Chan et al				
MP	AC	5,930,107	07/199	99	Rajeevakumar				-
MP	AD	6,232,202B1	05/200	01	Hong	-			-
MP	AE	6,256,248B1	07/200	01	Leung				
MP	AF	6,420,226B1	07/200	02	Chan et al	_			
MP	AG	6,468,855B2	10/200	)2	Leung et al				
MP	АН	6,509,595B1	01/200	03	Leung et al	-			-
MP	ΑI	6,573,548B2	06/200	23	Leung et al				-
	AJ								
FOREIGN PATENT DOCUMENTS									
EXAMINER INITIAL		DOCUMENT NO.	DATE		COUNTRY	CLA	ہ ا	UB TRANSLATION YES/NO	
	AK								
	AL								
	AM								
	AN								
OTHER ART (including Author, Title, Date, pertinent pages, etc.)									
MP	АО	"A 130 nm Generation High Density Etox™ Flash Memory Technology", Kenney, IEEE, IEDM 2001, pp. 41-44, December 2001							
	AP	•							
EXAMINER DATE CONSIDERED 6/05									
EXAMINER: Initial if reference considerage, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and									
not considered. Include copy of this form with next communication to application.									